

Estimation of the statistical distributions of lightning current parameters at ground level from the data recorded by instrumented towers

Paper TPWRD 00442-2002.R1

Alberto Borghetti

Carlo Alberto Nucci

University of Bologna Italy Mario Paolone

Outline of presentation

1. Introduction

The problem What has been done by other Authors

2. Numerical procedure for evaluating lightning current distributions at ground.

Application to the Berger's distributions and comparison with results obtained by other Authors

- 3. Application of the results to the evaluation of indirect lightning performance of overhead lines (not included in Transaction paper)
- 4. Conclusions

1.Introduction

The problem

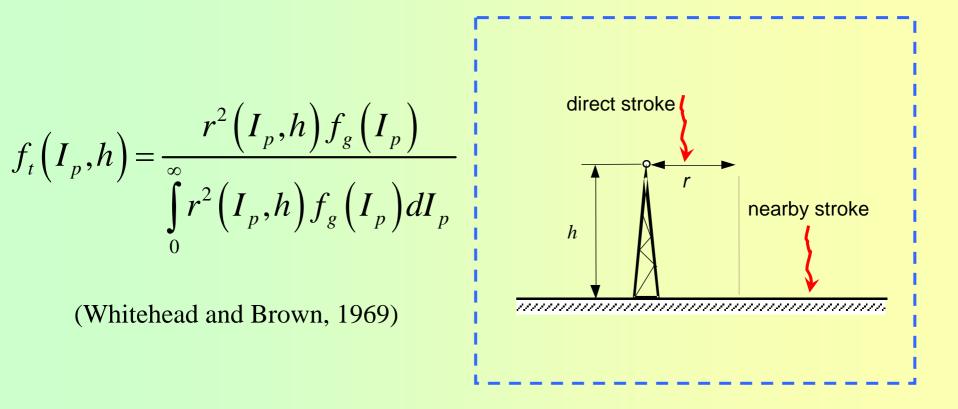
The probabilistic approach to power insulation coordination requires the knowledge of the statistical distributions of lightning current parameters.

The lightning current distributions currently used are those derived from experimental data gathered by means of elevated instrumented towers.

The '*attractive radius*' *r* of the tower tends to increase for flashes with larger currents

lightning current amplitudes are 'biased' towards higher values.

General relations between pdf of lightning peak current to a tower and at ground



The problem is to determine f_g being f_t and h known

General relations between pdf of lightning peak current to a tower and at ground

$$f_t(I_p,h) = \frac{r^2(I_p,h)f_g(I_p)}{\int\limits_0^\infty r^2(I_p,h)f_g(I_p)dI_p}$$

(Whitehead and Brown, 1969)



Figure 18.5: Lightning initiated by an upward-moving leader from a tower on Mt. San Salvatore near Lugano, Switzerland. Photographs of other discharges to the tower are shown in Fig. 6.1a, b. (Courtesy, Richard E. Orville, State University of New York at Albany)

We shall <u>disregard current reflections at tower top and base</u>, although they can certainly alter the measured current (e.g. *Guerrieri* et al, IEEE Trans. PWDR, 1998; *Rachidi* et al., JGR, 2003) and <u>we shall focus on</u> <u>downward discharges, assuming them perpendicular to flat ground</u>.

Studies performed by other Authors

The problem has been studied by several Authors, e.g.

Sargent [IEEE Trans PAS, Sept/Oct 1972],

by using an attractive-radius three-dimensional electrogeometric model and on the basis of the lightning current amplitude experimental data available at that time, derived a so-called synthetic current amplitude distribution to ground level, which, as shown by **Brown** [IEEE Trans PAS, Sept/Oct 1972], can be approximated by a lognormal distribution with μ_a =13 kA and σ_a =0.32.

Mousa and Srivastava [IEEE Trans. PWDR,1989], have proposed a lognormal distribution of current amplitudes at ground level with $\mu_q = 24$ kA and $\sigma_q = 0.31$.

Other forms of distribution have been investigated for the problem of interest by *Chisholm* et al. [*Proc. 1st PMAPS*, Toronto, Canada, 11-13 July 1986.

Here we shall focus on the analytical formula derived by *Pettersson* (see later).

Exposure of a tower to direct lightning

Lightning leader approaching ground: downward motion unperturbed unless critical field conditions develop \rightarrow juncture with the nearby tower, called *final jump*.

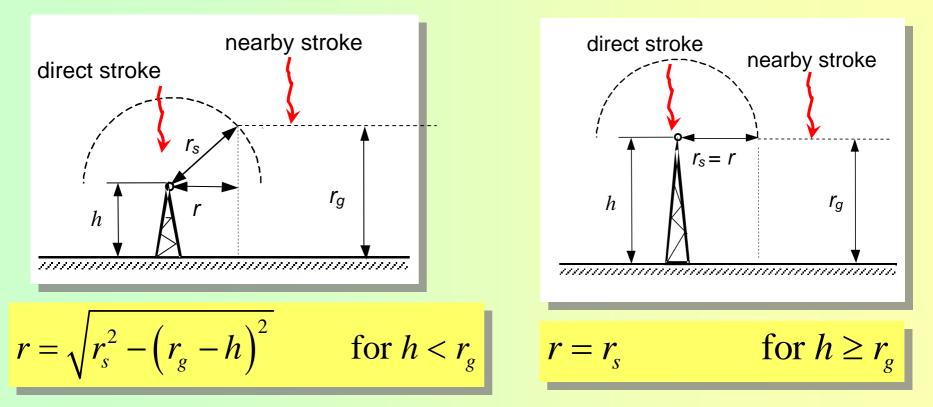
Assuming leader channel perpendicular to the ground plane \rightarrow the flash will stroke the tower if its *prospective* ground termination point, lies within the *attractive radius r*.

r depends on several factors, such as

- □ charge of the leader,
- □ its distance from the structure,
- type of structure (vertical mast or horizontal conductor),
- structure height,
- nature of the terrain (flat or hilly)
- ambient ground field due to cloud charges.

Several expressions have been proposed to evaluate such a radius. Some of them are based on the *electrogeometric model*.

Electrogeometrical expressions describing the exposure of a tower to direct lightning



Where r_s and r_g are the so called '*striking distances*' to the structure and to ground respectively.

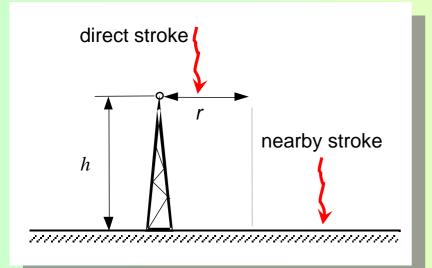
$$r_s = \alpha \cdot I_p^{\ \beta}$$
 $r_g = k \cdot r_s$

Electrogeometrical expressions describing the exposure of a tower to direct lightning

Electrogeometrical Attractive radius expression	α	β	k
Armstrong and Whitehead	6.7	0.80	0.9
IEEE	10	0.65	0.55
	1		

$$r_s = \alpha \cdot I_p^{\ \beta}$$
 $r_g = k \cdot r_s$

Other expressions describing the exposure of a tower to direct lightning



They have been inferred, by regression analysis, from the results of more complex and physically-oriented models than the Electrogeometric one.

A formula of the following type can be used

$$r = c + a \cdot I_p^b$$

Model	С	а	b
Eriksson	0	0.84 h ^{0.6}	0.76
from Rizk	0	2.83 h ^{0.4}	0.63
from Dellera-Garbagnati *	3h0.6	0.80	0.9

* The values reported have been derived by M. Bernardi, by interpolation of plots of the lateral distance of a slim structure vs. its height (in the range 5 to 100 m), calculated using the leader progression model of Dellera-Garbagnati

Studies performed by other Authors *Cont.* Analytical relation between pdf of lightning peak current to a tower and at ground We now focus on the analytical formula derived by *Petterson* [IEEE Trans. PWDR,1991]

1st hypothesis:

$$r(I_p,h) = a \cdot I_p^b$$

2nd hypothesis:

$$f_{g}(I_{p}) = \frac{1}{I_{p}\sigma_{g}} \frac{1}{\sqrt{2\pi}} \exp\left[-\frac{1}{2}\left(\frac{1}{\sigma_{g}}\ln(I_{p}/\mu_{g})\right)^{2}\right] = \frac{1}{I_{p}\sigma_{g}}\phi\left[\frac{1}{\sigma_{g}}\ln(I_{p}/\mu_{g})\right]$$
$$f_{t}(I_{p},h) = \frac{r^{2}(I_{p},h)f_{g}(I_{p})}{\int_{0}^{\infty}r^{2}(I_{p},h)f_{g}(I_{p})dI_{p}} = \frac{a^{2}}{\int_{0}^{\infty}r^{2}(I_{p},h)f_{g}(I_{p})dI_{p}}\left[\frac{1}{\sigma_{g}}\ln(I_{p}/\mu_{g})\right]$$
$$\exp(2b\ln I_{p})$$

Studies performed by other Authors *Cont.* **Analytical relation between pdf of lightning peak current to a tower and at ground** We now focus on the analytical formula derived by *Petterson* [IEEE Trans. PWDR,1991]

1st hypothesis:

$$r(I_p,h) = a \cdot I_p^b$$

2nd hypothesis:

$$f_{g}(I_{p}) = \frac{1}{I_{p}\sigma_{g}} \frac{1}{\sqrt{2\pi}} \exp\left[-\frac{1}{2}\left(\frac{1}{\sigma_{g}}\ln(I_{p}/\mu_{g})\right)^{2}\right] = \frac{1}{I_{p}\sigma_{g}}\phi\left[\frac{1}{\sigma_{g}}\ln(I_{p}/\mu_{g})\right]$$

$$f_{t}(I_{p},h) \text{ is lognormal}$$

$$\mu_{t} = \mu_{g}\left[\exp\left(b\cdot\sigma_{g}^{2}\right)^{2}\right] \qquad \sigma_{g} = \sigma_{t}$$
Pettersson's formula

2. Numerical procedure for evaluating lightning current distributions at ground.

Proposed numerical procedure for evaluating lightning current distributions at ground

*I_p** minimum peak current observed

*r** its attractive radius

All the strokes with perspective stroke location within $2\pi r^{*2}$ are collected by the tower

- I. Generation of a population of events I_p , t_f ,... and $x_g \in [0, r(I_p)]$ - I_p , t_f ... are generated from the p.d.f. of strokes to the tower - x_g are generated assuming the stroke locations be uniformly distributed (correlations are taken into account)
- II. Selection of the events with $x_g < r^*$
- III. Determination of the statistical distributions of the current parameters related to such events

			TABLEAU 1						
		Re Sum	sumé des par mary of fron	ametres du fi <i>shape paran</i>	neters				
Paramètre Parameter	N Unités N Units		Approximation par une distribution log-normale Approximation by log-normal distribution		la ⁻ Percer	rcentage de ca valeur du tabl est dépassée at of cases exc vabulated valu	eau ceeding		
		-	μ	σlog	Test positif Positive test	95 %	50 %	5 %	
Décharges principales					++				1
First stroke T-10	80	μs	4,5	0,25	non no	1,8	4,5	11,3	
T-30	80	μs	2,3	0,24	oui	0,9	2,3	5,8	
TAN-10	75	kA/µs	2,6	0,40	yes non	0,6	2,6	11,8	
S-10	75	kA/µs	5,0	0,28	no oui	1,7	5,0	14,1	
S-30	73	kA/μs	7,2	0,27	yes oui	2,6	7,2	20,0	
TAN-G	75	kA/μs	24,3	0,26	yes oui	9,1	24,3	65,0	
PEAK-1	75	kA	27,7	0,20	- yes oui	12,9	27,7	59,5	İ
PEAK	80	kA	31,1	0,21	yes non	14,1	31,1	68,5	Ţ
RATIO (P-1)/P	-	-	0,9	0,10	no -	~		-	
Décharges secondaires								1	
Subsequent strokes T-10	114	μs	0,6	0,40	non	0,1	0,6	2,8	
T-30	114	μs	0,4	0,44	no non	0,1	0,4	1,8	
TAN-10	108	kA/μs	18,9	0,61	no oui	1,9	18,9	187,4	
S-10	114	kA/µs	15,4	0,41	yes oui	3,3	15,4	72,0	
S-30	114	kA/μs	20,1	0,42	yes oui	4,1	20,1	98,5	
TAN G	113	kA/μs	39,9	0,37	yes oui	9,9	39,9	161,5	
PEAK-1	114	kA	11,8	0,23	yes oui	4,9	11,8	28,6	
PEAK	114	kA	12,3	0,23	yes oui	5,2	12,3	29,2	
RATIO (P-1)/P	-	-	0,9	0,09	yes				

Remarque : Dans chaque cas, les distributions sont exprimées en base 10.

			TABLEAU	– TABLE I	,				-
		Re	ésumé des par	amètres du fi	ont				
	.	Sum	mary of from	t shape paran	neters				1
Paramètre Parameter	N Unités N Units		Approximation par une distribution log-normale Approximation by log-normal distribution		la [.] Percer	rcentage de ca valeur du table est dépassée at of cases exc vabulated value	eau eeding		
			μ	σlog	Test positif Positive test	95 %	50 %	5 %	
Décharges principales					1				1
First stroke T-10	80	μs	4,5	0,25	non no	1,8	4,5	11,3	
T-30	80	μs	2,3	0,24	oui	0,9	2,3	5,8	
TAN-10	75	kA/µs	2,6	0,40	yes non	0,6	2,6	11,8	
S-10	75	kA/µs	5,0	0,28	no oui	1,7	5,0	14,1	
S-30	73	kA/μs	7,2	0,27	yes oui	2,6	7,2	20,0	
TAN-G	75	kA/μs	24,3	0,26	yes oui	9,1	24.3	65,0	
PEAK-1	75	kA	27,7	0,20	oui	12,9	27,7	59,5	Ī
PEAK	80	kA	31,1	0,21	yes non	14,1	<i>27,1</i>	68,5	Ī
RATIO (P-1)/P		-	0,9	0,10	no -	~		-	
Décharges secondaires Subsequent strokes	114		0,6	0,40		0,1	0,6	2,8	
T-10		μs			non no				
T-30	114	μs	0,4	0,44	non	0,1	0,4	1,8	
TAN-10	108	kA/μs	18,9	0,61	oui yes	1,9	18,9	187,4	
S-10	114	kA/μs	15,4	0,41	oui	3,3	15,4	72,0	
S-30	114	kA/μs	20,1	0,42	yes oui	4,1	20,1	98,5	
TAN G	113	kA/μs	39,9	0,37	yes oui yes	9,9	39,9	161,5	
PEAK-1	114	kA	11,8	0,23	oui	4,9	11,8	28,6	
PEAK	114	kA	12,3	0,23	yes oui	5,2	12,3	29,2	
RATIO (P-1)/P	_	-	0,9	0,09	yes		122		

Remarque : Dans chaque cas, les distributions sont exprimées en base 10.

			TABLEAU 1	– TABLE I					
		Ré Sum	ésumé des par mary of fron	amètres du fr t <i>shape param</i>	ont seters				
Paramètre Parameter	N Unités N Units		Approximation par une distribution log-normale Approximation by log-normal distribution			la Percer	rcentage de ca valeur du tabl est dépassée nt of cases exc tabulated valu	eau ceeding	
			μ	σ log	Test positif Positive test	95 %	50 %	5 %	
Décharges principales First stroke T-10	80	μs	4,5	0,25	non	1,8	4,5	11,3	
T-30	80	μs	2,3	0,24	oui	0,9	2,3	5,8	1-1
TAN-10	75	kA/µs	2,6	0,40	yes non no	0,6	2,6	11,8	
S-10	75	kA/µs	5,0	0,28	oui	1,7	5,0	14,1	
S-30	73	kA/μs	7,2	0,27	yes oui yes	2,6	7,2	20,0	
TAN-G	75	kA/μs	24,3	0,26	oui	9,1	24,3	65,0	
PEAK-1	75	kA	27,7	0,20	yes oui yes	12,9	27,7	59,5	
PEAK	80	kA	31,1	0,21	non	14,1	31,1	68,5	
RATIO (P-1)/P		-	0,9	0,10	no —	~	-	-	
Décharges secondaires Subsequent strokes T-10	114	μs	0,6	0,40	non	0,1	0,6	2,8	
Т-30	114	μs	0,4	0,44	no non	0,1	0,4	1,8	
TAN-10	108	kA/µs	18,9	0,61	no oui yes	1,9	18,9	187,4	
S-10	114	kA/μs	15,4	0,41	oui	3,3	15,4	72,0	
S-30	114	kA/μs	20,1	0,42	yes oui	4,1	20,1	98,5	
TAN G	113	kA/μs	39,9	0,37	yes oui	9,9	39,9	161,5	
PEAK-1	114	kA	11,8	0,23	yes oui	4,9	11,8	28,6	
РЕАК	114	kA	12,3	0,23	yes oui yes	5,2	12,3	29,2	
RATIO (P-1)/P	_	-	0,9	0,09	,03				

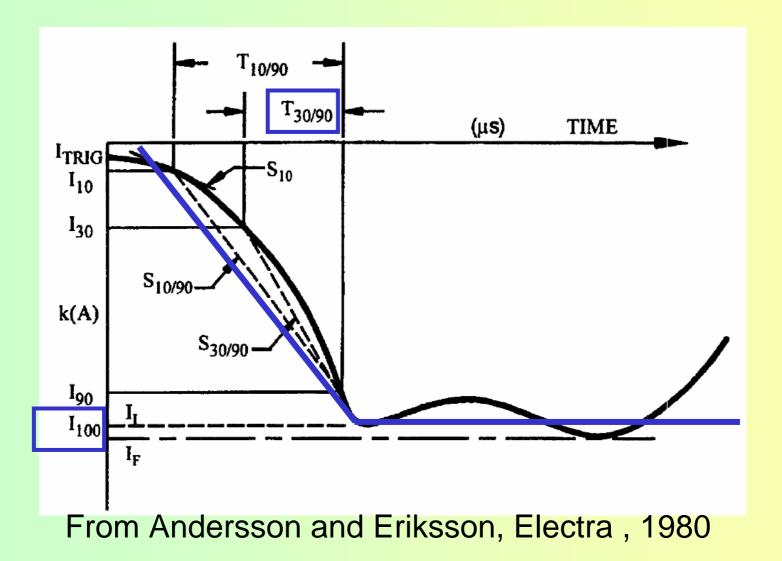
Remarque : Dans chaque cas, les distributions sont exprimées en base 10.

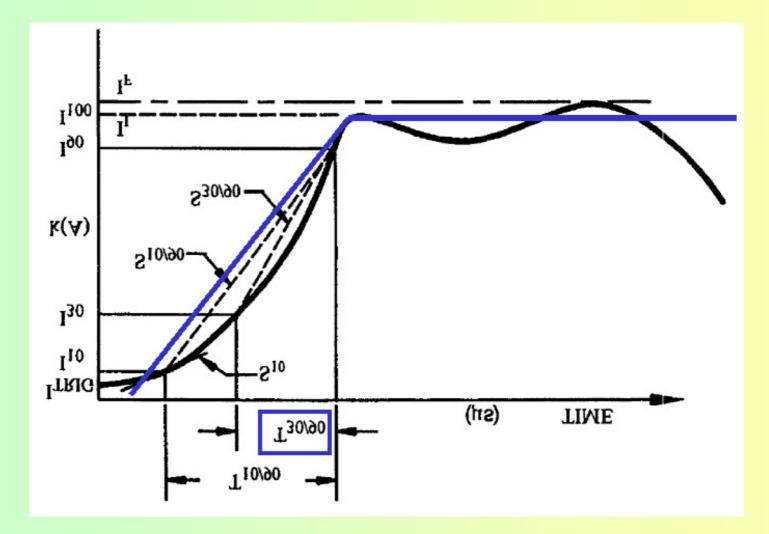
5

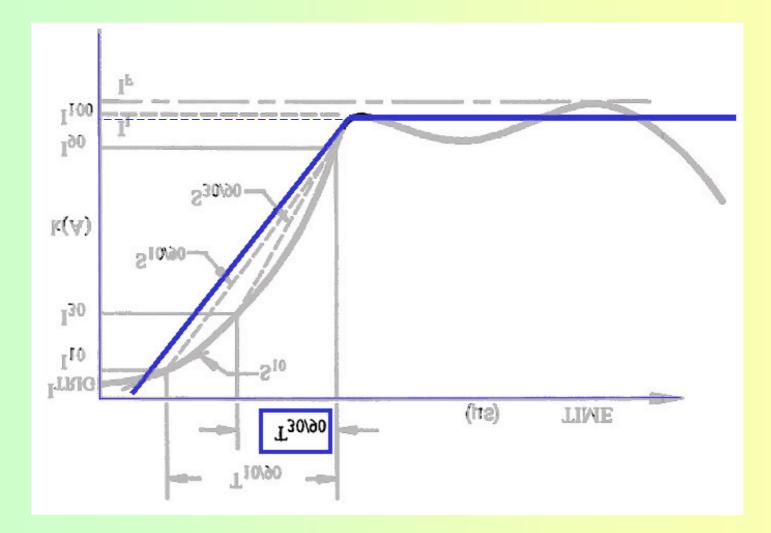
			TABLEAU 1	– TABLE I					
			ésumé des par <i>mary of fron</i> t						
Paramètre Parameter	N N	Unités UnitésApproximation par une distributionPourcentage de cau la valeur du table est dépassée Percent of cases exce log-normal distribution			une distribution log-normale Approximation by			eau reeding	
			μ	σ log	Test positif Positive test	95 %	50 %	5 %	
Décharges principales First stroke T-10	80	μs	4,5	0,25	non	1,8		11,3	
T-30	80	μs	2,3	0,24	no	0,9	2,3	5,8	33
TAN-10	75	kA/µs	2,6	0,40	yes non no	0,6	2,6	11,8	
S-10	75	kA/µs	5,0	0,28	oui	1,7	5,0	14,1	
S-30	73	kA/μs	7,2	0,27	yes oui	2,6	7,2	20,0	
TAN-G	75	kA/μs	24,3	0,26	yes oui	9,1	24,3	65,0	
PEAK-1	75	kA	27,7	0,20	yes oui	12,9	27,7	59,5	
PEAK	80	kA	31,1	0,21	yes non	14,1	31,1	68,5	
RATIO (P-1)/P	-	-	0,9	0,10	no -	~		-	
Décharges secondaires Subsequent strokes T-10	114	μs	0,6	0,40	non	0,1	0,6	2,8	
T-30	114	μs	0,4	0,44	no non	0,1	0,4	1,8	
TAN-10	108	kA/µs	18,9	0,61	no oui	1,9	18,9	187,4	
S-10	114	kA/µs	15,4	0,41	yes oui	3,3	15,4	72,0	
S-30	114	kA/μs	20,1	0,42	yes oui	4,1	20,1	98,5	
TAN G	113	kA/μs	39,9	0,37	yes oui	9,9	39,9	161,5	
PEAK-1	114	kA	11,8	0,23	yes oui	4,9	11,8	28,6	
PEAK	114	kA	12,3	0,23	yes oui	5,2	12,3	29,2	
RATIO (P-1)/P	_	-	0,9	0,09	yes				

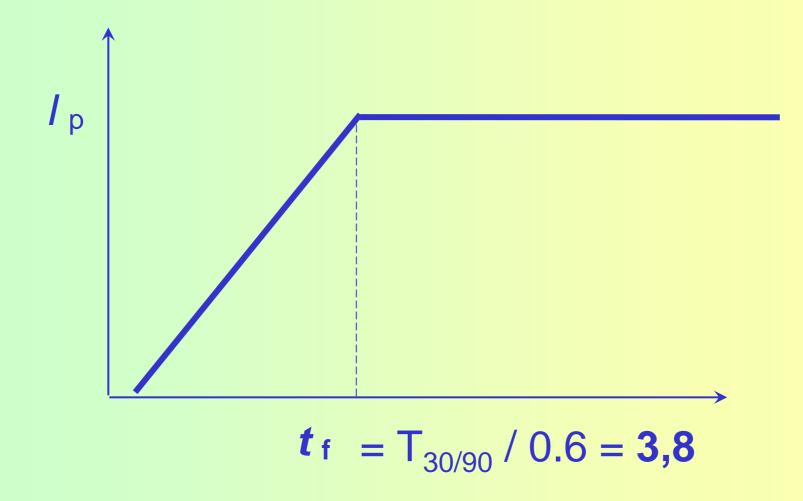
Remarque : Dans chaque cas, les distributions sont exprimées en base 10.

Ę







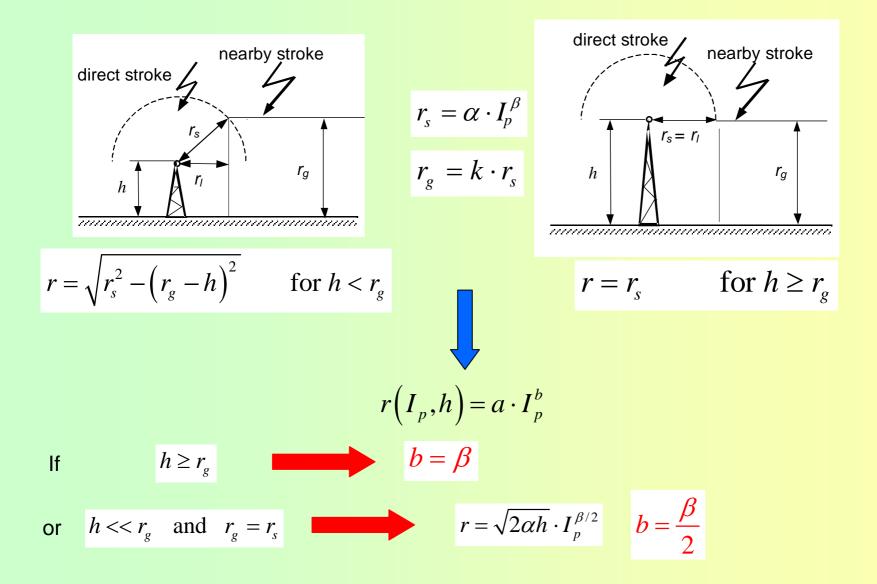


Parameter		μ_t		σ_t	 (17
First Peak Ip (kA)			27.7		$P_t = 0$).47
Front duration t _f	3.8	3.8				
Attractive radius expression $r(I_p,h) = a \cdot I_p^b$	а			b		
Eriksson	0.84 h ^{0.}	6		0.76		
Rizk	2.83 h ^{0.}	4		0.63		

Para	neter	Expression			
		Eriksson	Rizk		
	μ_g	20.1	21.3		
I _ρ (kA)	σ_{g}	0.20	0.20		
	μ_{g}	3.2	3.3		
t _f (μs)	σ_{g}	0.24	0.24		
	$ ho_{g}$	0.48	0.47		

		Parameter		μ	t	σ_t		0.47
ĺ	Fin	st Peak I_{ρ} (k	A)	27.	.7	0.20	ρ_t	= 0.47
	Fron	t duration t_f	(μs)	3.8	8	0.24		
	expre	Attractive radius expression $r(I_p,h) = a \cdot I_p^b$		а		b		
	Eriksson		0.84 h ^{0.}	6		0.76		
	Rizk		2.83 h ^{0.}		0.63			
		P	arameter					
Pettersson	's formula				Eri	ksson		Rizk
Г	$(-2)^2$		μ _g		20.1	20.0	21.3	21.2
$\mu_t = \mu_g \left[\exp \left(b \cdot \sigma_g^2 \right)^2 \right]$		I _p (kA)	σ_{g}		0.20	0.20	0.20	0.20
$\sigma_g = \sigma_t$	$\sigma_g = \sigma_t$		μ _g			3.2		3.3
			σ_{g}		0.24			0.24
			$ ho_{g}$	ρ_g		0.48		0.47

Comparison with the Pettersson's formula for the case of electrogeometric expressions



		Parameter		μ_t	σ	t	$\rho_{t} = 0.47$
	F	irst Peak I _p (kA)	27.7	0.2	20	$p_t = 0.47$	
	Front duration t_f (µs)			3.8	0.2	24	
Attract	eometrical ive radius ression	α		β			k
	rong and tehead	6.7	0.80		0.9		0.9
IEEE	(1243)	10		0.65			0.55

Para	meter	Expression			
		A&W	IEEE		
	μ_{g}	20.2	21.1		
$I_{ ho}(kA)$	σ_{g}	0.21	0.20		
	μ_g	3.2	3.3		
t _f (μs)	σ_{g}	0.24	0.24		
	$ ho_{g}$	0.49	0.47		

		Parameter		μ_t	σ	t	$\rho_{t} = 0.47$
	F		27.7	0.2	20	$p_t = 0.47$	
	Front duration $t_f(\mu s)$			3.8	0.2	24	
Attract	geometrical ive radius ression	α		β			k
Armstrong and Whitehead		6.7	0.80		0.9		0.9
	EEE	10		0.65			0.55

Parameter		Expression						
		A&W				IEEE		
I _p (kA)	μ_g	20.2	b= β /2 23.4	b=β 19.7	21.1	b= β /2 24.1	b=β 21.0	
	$\sigma_{\!g}$	0.21	0.20	0.20	0.20	0.20	0.20	
Probability that conditions are verified			4.2%	28.8%		0.02%	80%	

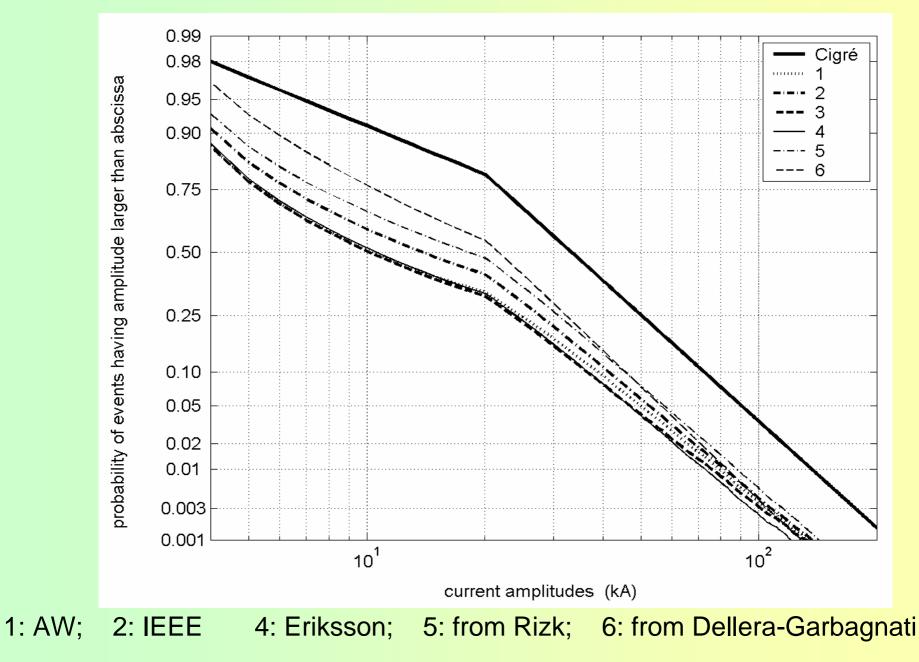
	Parameter		μ_t	σ	t	$\rho_{t} = 0.47$	
	First Peak I _p (kA)			27.7	0.2	20	$p_t = 0.47$
	Front duration t_f (µs)		3.8	0.2	24		
	ive radius ression $= c + a \cdot I_p^b$	С		а			b
From Dellera & Garbagnati		3h0.6		0.80			0.9

Para	Dellera & Garbagnati Expression	
	μ_{g}	22.1
I _ρ (kA)	σ_{g}	0.19
	μ_g	3.4
t _f (μs)	σ_{g}	0.24
	$ ho_{ m g}$	0.45

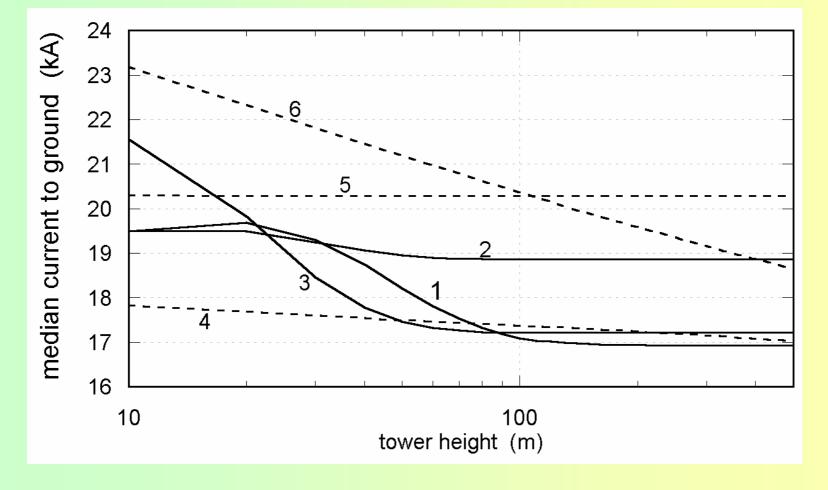
		Parameter		μ_t	σ	t	$\rho_{t} = 0.47$	
	First Peak I _p (kA)			27.7	0.2	20	$p_t = 0.47$	
	Front duration t_f (µs)			3.8	0.2	24		
		ive radius ression $= c + a \cdot I_p^b$	С		а			b
From Dellera & Garbagnati			3h0.6		0.80			0.9

Pettersson's formula	Parar	Dellera & Garbagnati Expression	
Pettersson s formula		μ_{g}	22.1 18.1
$\mu_t = \mu_g \left[\exp \left(b \cdot \sigma_g^2 \right)^2 \right]$	I _p (kA)	σ_{g}	0.19
		μ_{g}	3.4
$\sigma_g = \sigma_t$	t _f (μs)	σ_{g}	0.24
		$ ho_{ m g}$	0.45

Application to the CIGRE distribution



Influence of the Tower Height



1: AW; 2: IEEE 4: Eriksson; 5: from Rizk; 6: from Dellera-Garbagnati

First Conculsions

The proposed method is more general than the other proposed so far in the literature.

What are the applications?

3. Application of the results to the evaluation of indirect lightning performance of overhead lines

Application of the results to the evaluation of indirect lightning performance of overhead lines

- The _____ is represented by the following curve:
 - Annual number of induced voltages exceeding the value in abscissa (or Annual number of flashovers)

Lightning Performance of a Distribution Line relevant to <u>induced</u> voltages

VOLTAGE [kV] (or CFO)

Application of the results to the evaluation of indirect lightning performance of overhead lines Cont.

How to calculate the ____?

Clearly, the ____ depends on:

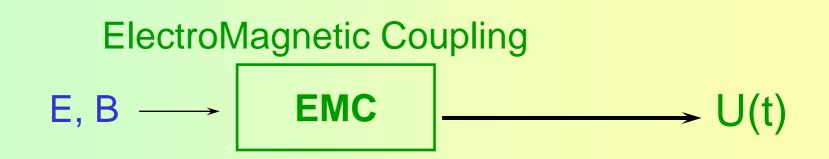
models used to calculate the induced voltages

lateral distance expression

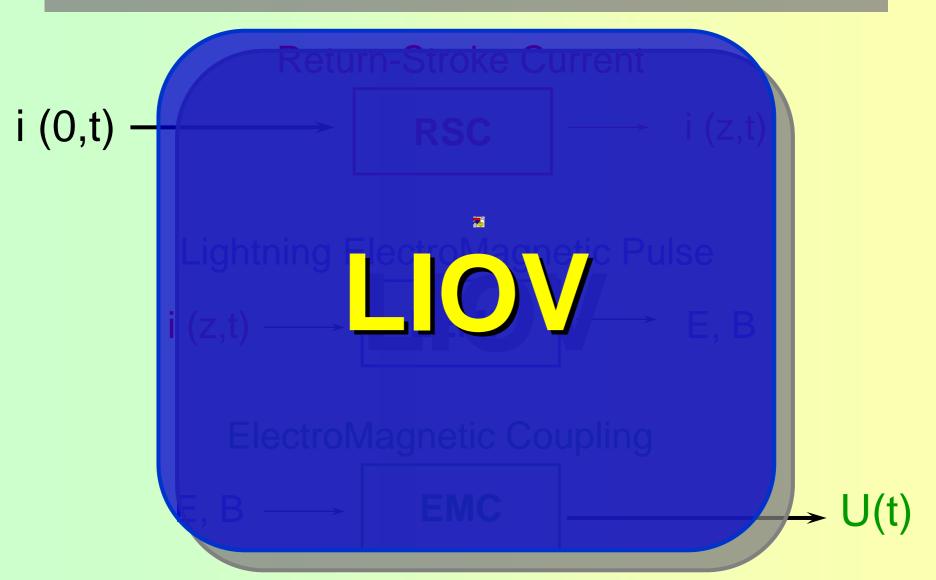
statistical distribution of lightning parameters

Models used to calculate the induced voltages Return-Stroke Current $i(0,t) \longrightarrow RSC \longrightarrow i(z,t)$

Lightning ElectroMagnetic Pulse i (z,t) \longrightarrow LEMP \longrightarrow E, B



Models used to calculate the induced voltages





LIOV code

Models

- <u>Return-stroke model</u>: MTLE (and TL)
- LEMP: Uman and McLain and Cooray-Rubinstein
- <u>Coupling model</u>: Agrawal extended to the case of lossy ground

This allows to take into account **more realistic line configurations** than the simplified Rusck expression

The Agrawal coupling model

$$\frac{\partial}{\partial x}v_{i}^{s}(x,t) + L'_{ij}\frac{\partial}{\partial t}i_{i}(x,t) + \int_{0}^{t}\xi_{g}^{'}(t-\tau)\frac{\partial i(x,\tau)}{\partial \tau} = E_{x}^{i}(x,t,h)$$
$$\frac{\partial}{\partial x}i_{i}(x,t) + C'_{ij}\frac{\partial}{\partial t}v_{i}^{s}(x,t) = 0$$

Transmission line coupling equations (Agrawal et al.)

Overhead line above lossy ground

The Agrawal coupling model

$$\frac{\partial}{\partial x}v_{i}^{s}(x,t) + L'_{ij}\frac{\partial}{\partial t}i_{i}(x,t) + \int_{0}^{t}\xi_{g}^{i}(t-\tau)\frac{\partial i(x,\tau)}{\partial \tau} = \begin{bmatrix} E_{x}^{i}(x,t,h) \\ \frac{\partial}{\partial x}i_{i}(x,t) + C'_{ij}\frac{\partial}{\partial t}v_{i}^{s}(x,t) = 0 \end{bmatrix}$$

The ground resistivity plays a role in

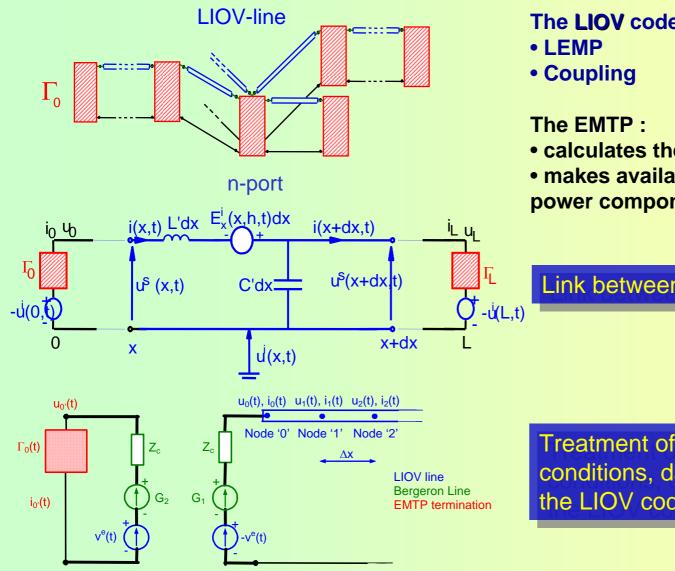
- 1) the calculation of the line parameters
- 2) the calculation of the electromagnetic field

- The LIOV code allows for the calculation of lightning-induced voltages along a multiconductor overhead line as a function of
- lightning current waveshape (amplitude, front steepness, and duration),
- return stroke velocity,
- line geometry (height, length, number and position of conductors), values of resistive terminations,
- ground resistivity and relative permittivity.
- It allows also taking into account induction phenomena due to
- the leader field,
- non-linear phenomena such as corona
- and the presence of surge arresters.

In order to take into account the presence of more complex types of terminations, as well as of line discontinuities and complex system topologies, the LIOV code has been interfaced with EMTP96.

Link of the LIOV code with EMTP96

Concept at the basis of the interface



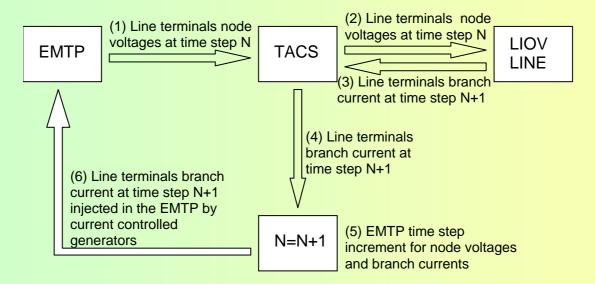
The LIOV code calculates:

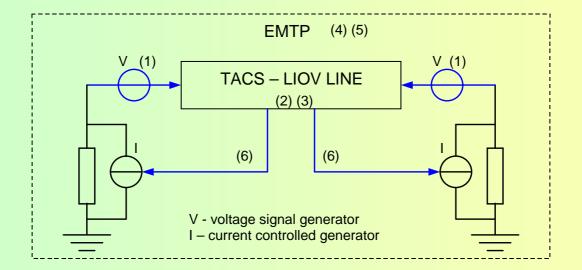
- calculates the boundary conditions
- makes available a large library of power components

Link between LIOV and EMTP

Treatment of the boundary conditions, data exchange between the LIOV code and the EMTP96:

Link of the LIOV code with EMTP96





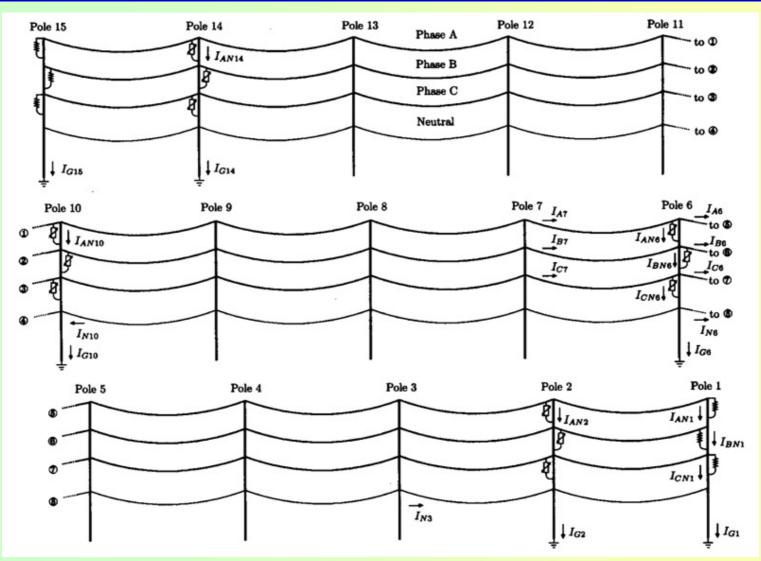
Comparison with data measured on real scale complex line model at the ICLRT of the University of Florida (July-August 2002/2003)



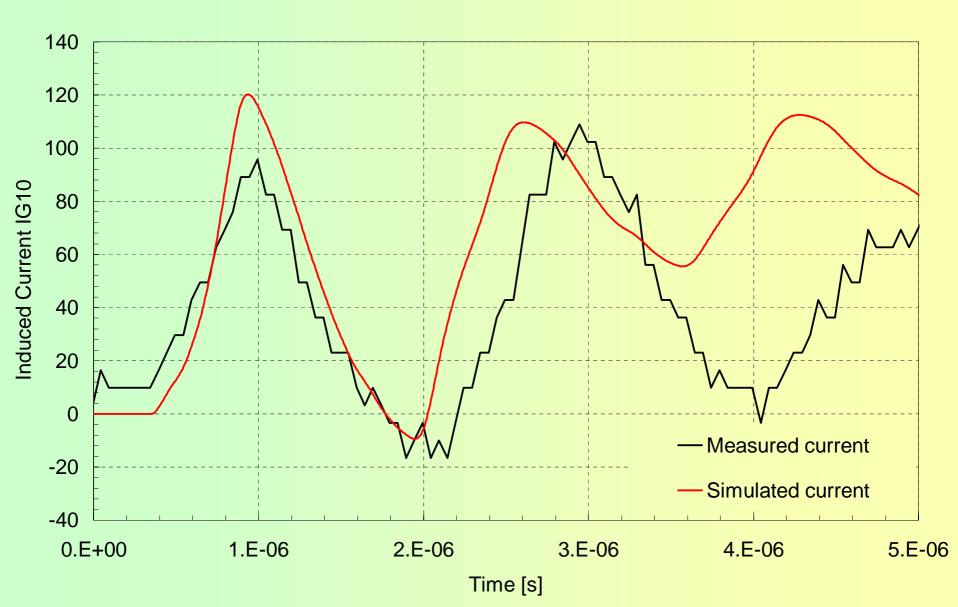


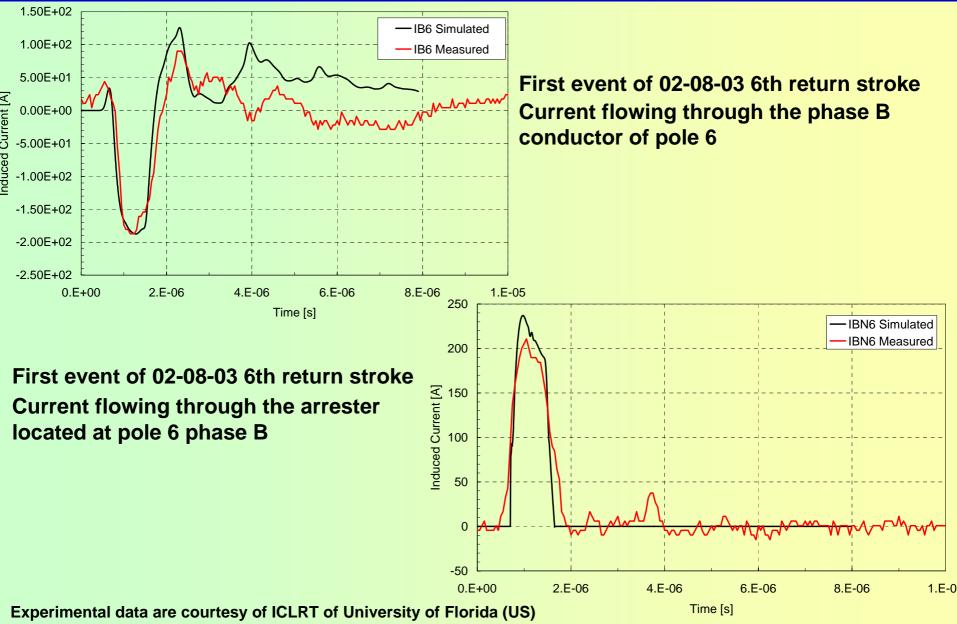
Surge arrester characteristic

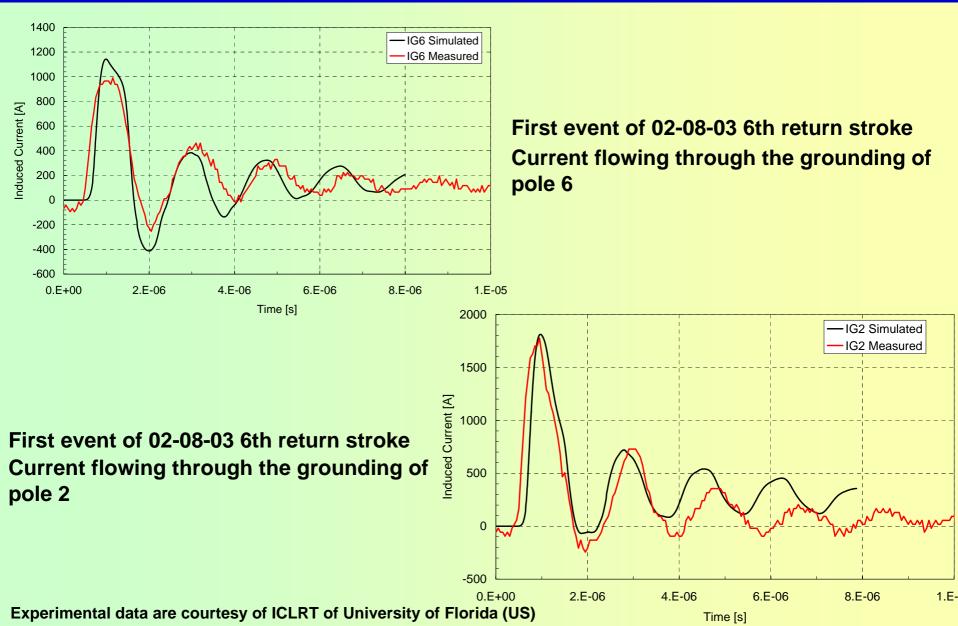




Experimental overhead distribution line installed at the ICLRT. The indicated quantities are the measured lightning-induced currents.







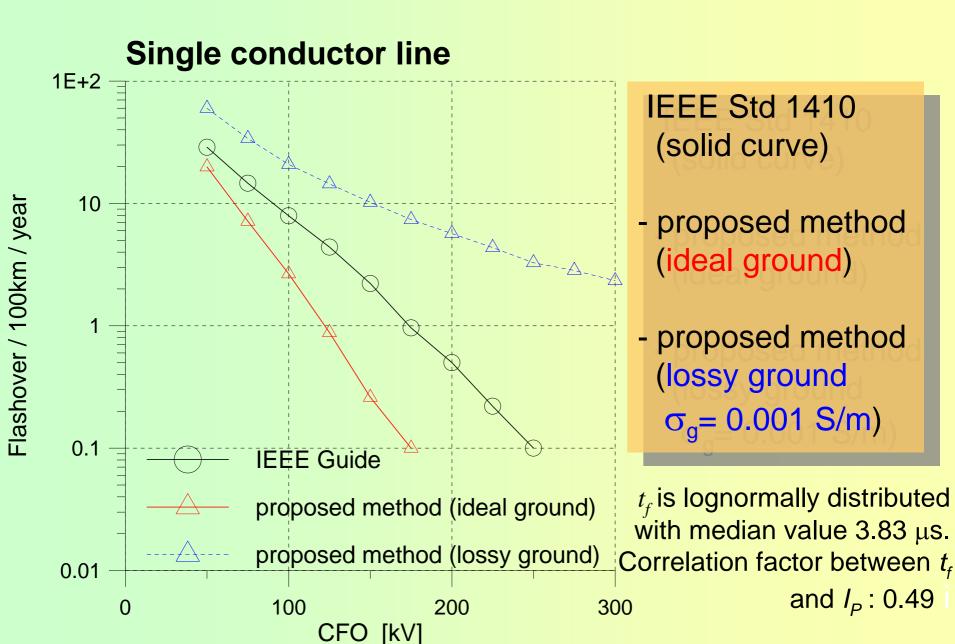
Clearly, the ____ depends on:

models used to calculate the induced voltages

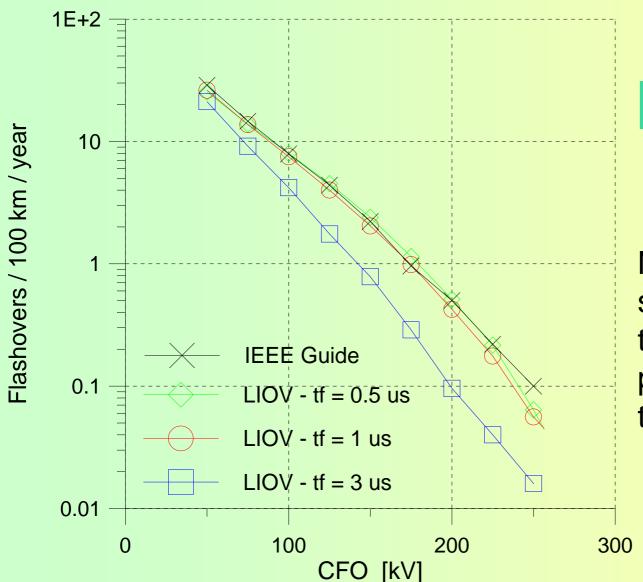
lateral distance expression

statistical distribution of lightning parameters

Comparison with IEEE Std 1410-1997



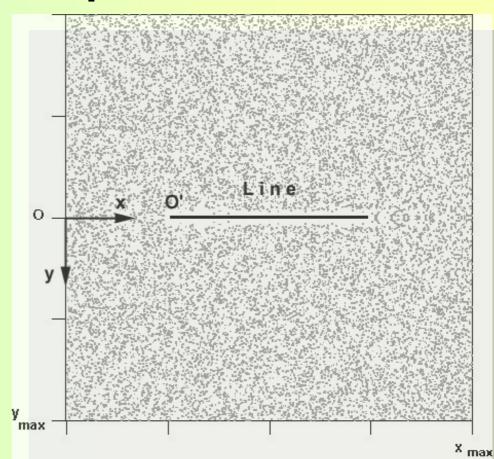
Comparison with IEEE Std 1410-1997



Ideal ground

Note that with small values of t_f the two methods predict basically the same results

- For the calculation of the indirect lighting performance of the overhead use is made of the procedure proposed by Borghetti and Nucci [ICLP, 1998; Sipda, 1999], based on the Monte Carlo method.
- Each event is characterized By 4 random variables
 - peak value of the lightning current Ip
 - front time t_{f} (correlated with I_n)
 - two co-ordinates of the stroke location (X and V)



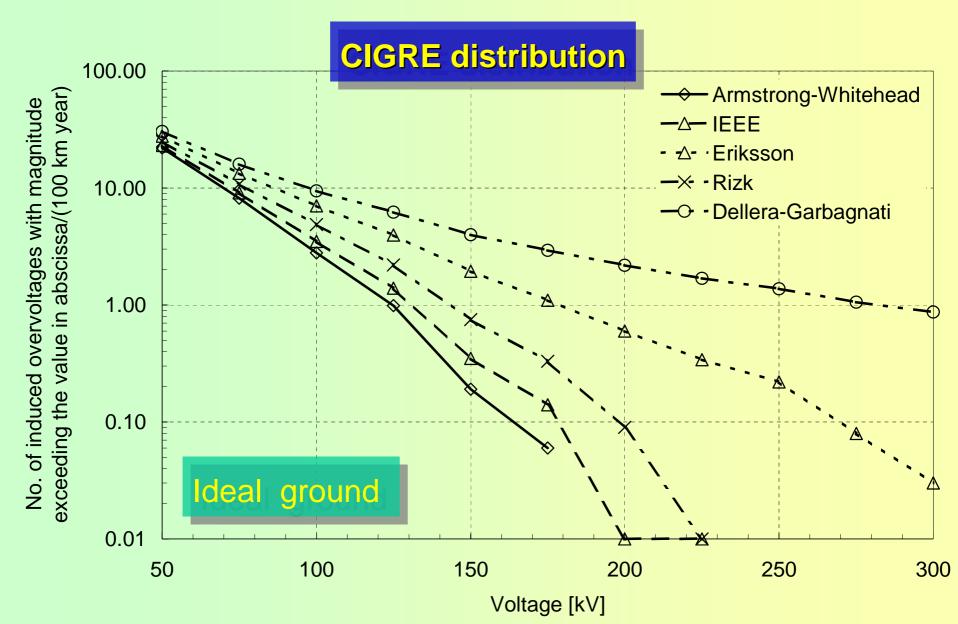
- 1 Inputs:
 - lightning current parameters (Ip and tf)
 - return stroke velocity
 - line and ground data
- 2 Random generation of events $(I_p; t_f : x; y) > 20000$
- 3 Induced overvoltage calculation using LIOV or LIOV-EMTP96
- 4 Counting of the events generating overvoltages greater than 1.5 x CFO
- 5 Plot the graph: No. of flashovers/100 km/year vs CFO where No. of flashovers/100 km/year = (n/n_{tot}) • n_g • S • 100/L (with n_g=ground flash density)

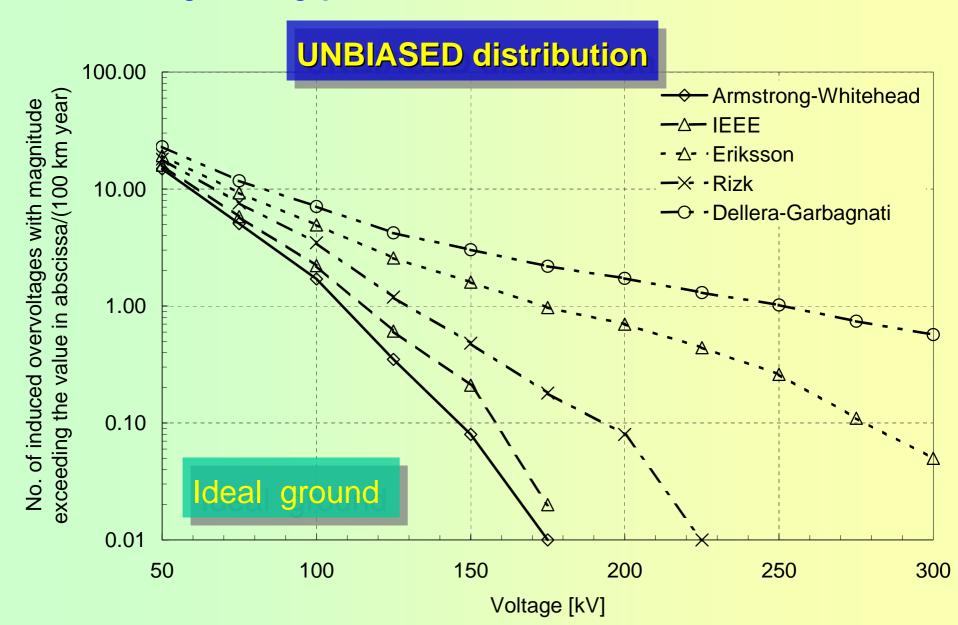
Let us now calculate the indirect lightning performance of an overhead line by using either:

the lightning current statistical distribution by *Berger* (CIGRE distribution) biased by the presence of the <u>tower</u>;
the statistical distributions <u>at ground</u> inferred using the proposed method.

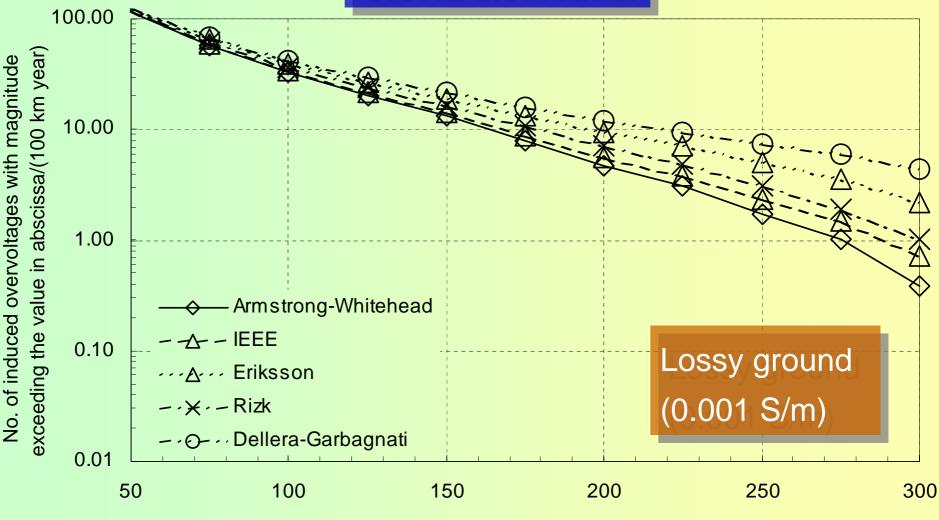
We consider a single-conductor overhead line with the following characteristics:

- 2 km long;
- 10 m high line;
- 'matched' at both end;
- "striking area" around the line about 20 km².



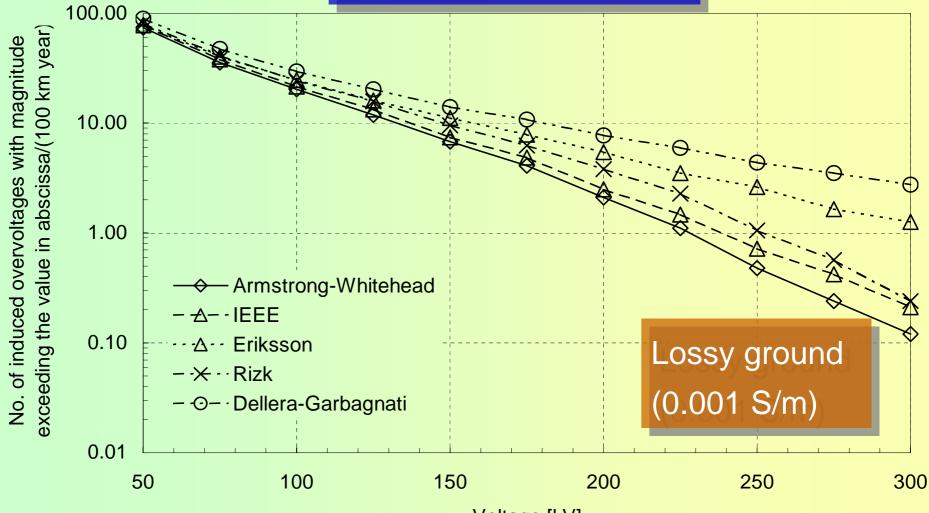


CIGRE distribution



Voltage [kV]

UNBIASED distribution



Voltage [kV]

Conclusions

The use of unbiased current statistical distributions results, as expected, in a better performance of the distribution line to indirect lightning, these distributions being characterized by a lower median value.

We have shown how the results vary depending on the expression adopted to evaluate the lateral distance (attractive radius).

Also, the ground resistivity acts in minimizing the difference between the line performance calculated using the biased and unbiased lightning current distributions.

Conclusions

It appears, however, that additional study on attractive radius expressions is badly needed.

The results obtained show that statistical current distributions at ground are probably characterized by lower median values than the relevant distributions gathered by means of instrumented towers.

This is in line with lower median values obtained by means of lightning location systems, although ...